

Gradient-Structured Ionic Bimodal Sensor with Giant Piezoionic and thermal-resistive effect for Crosstalk-Free Pressure-Temperature Perception

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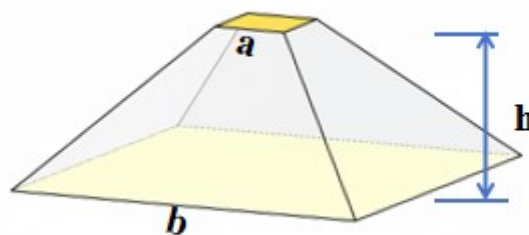


Figure S1. The scheme diagram of gradient structure with a trapeziform shape ($a=1$, $b=\sqrt{5}$, $h=2$)

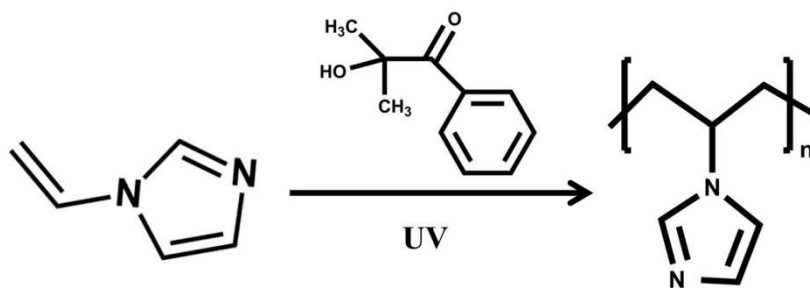


Figure S2. Reaction mechanism of PVM through a one-step photopolymerization.

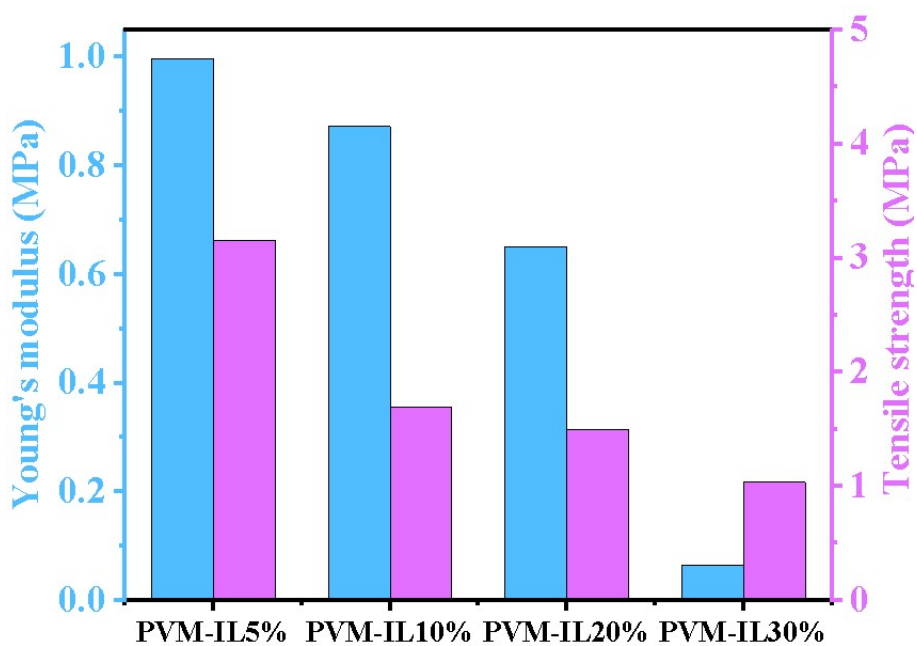


Figure S3. Mechanical performances of PVM+IL.

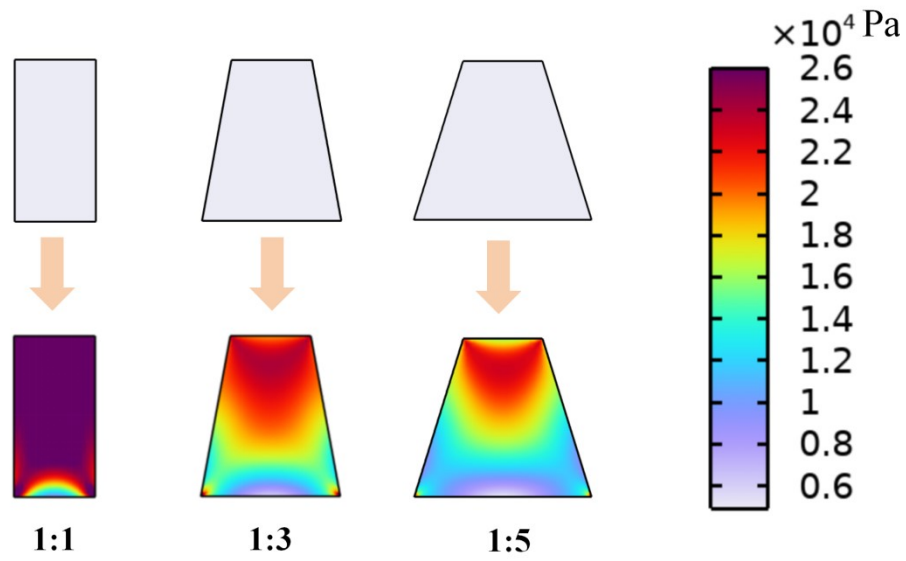


Figure S4. Stress Contour Plot of pressure gradient along the height for the structure with various area ratio obtained from COMSOL software.

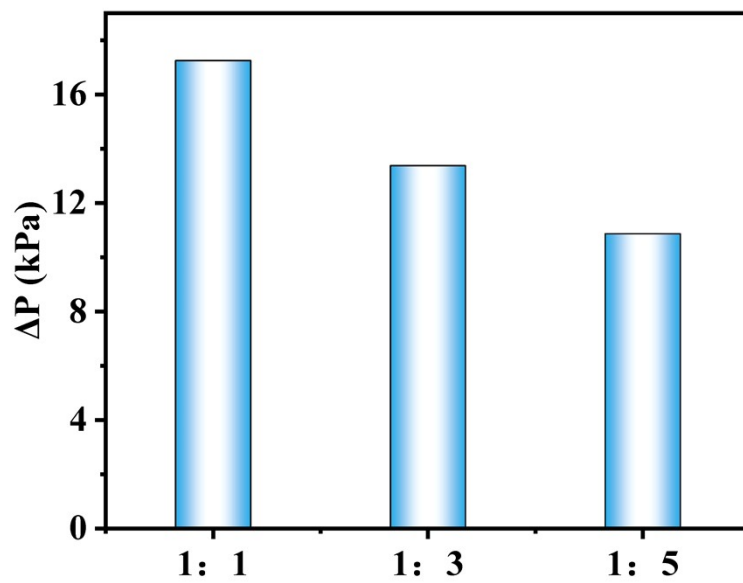


Figure S5. Pressure difference along the thickness for the structure with various area ratio obtained from COMSOL software.

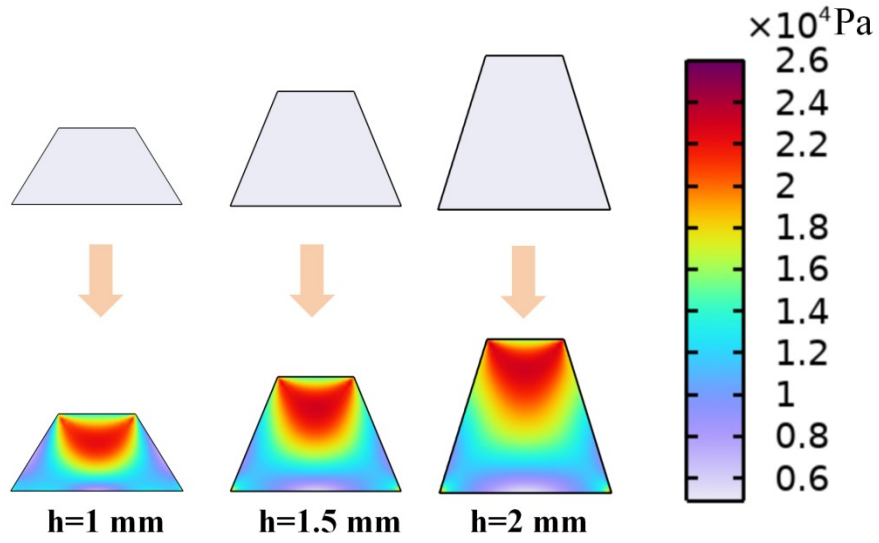


Figure S6. Stress Contour Plot of pressure gradient along the height for the structure with various heights (h) obtained from COMSOL software.

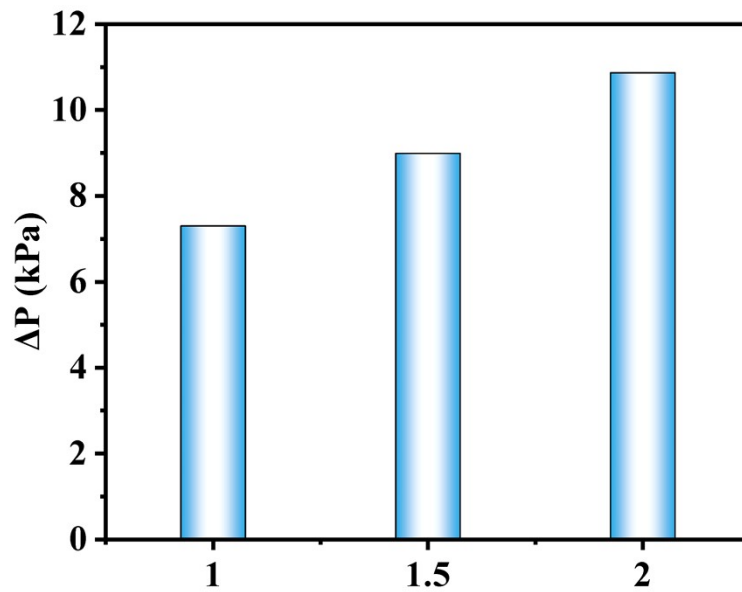


Figure S7. Pressure difference along the thickness for the structure with various heights obtained from COMSOL software.

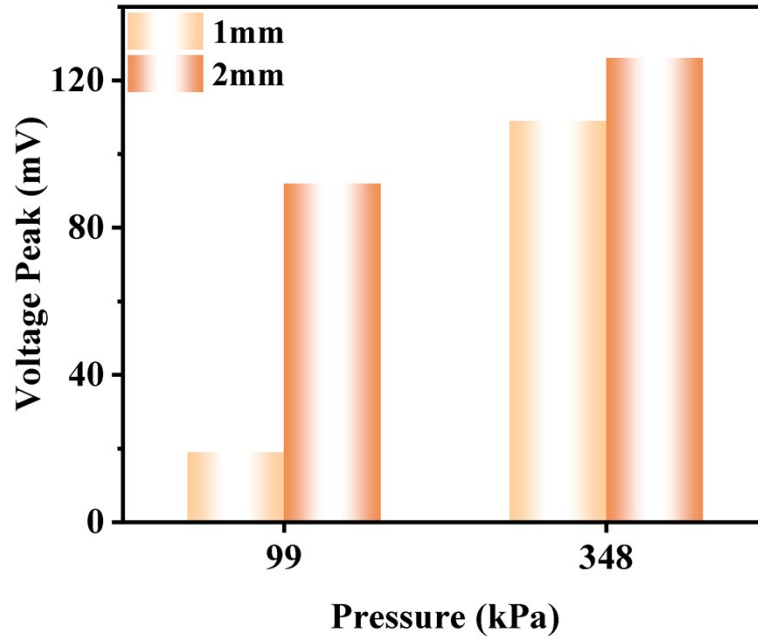


Figure S8. The comparison of piezoionic response in gradient-structure ionogels with various height.

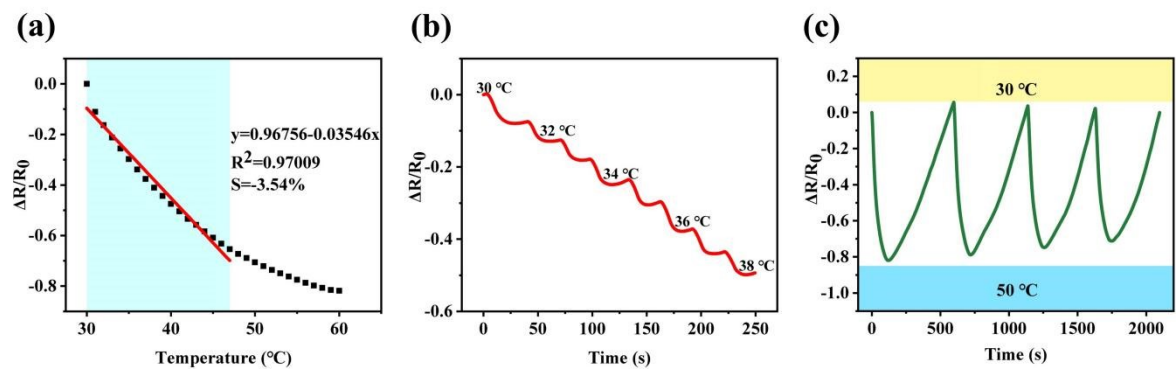


Figure S9. Temperature sensing performances of the bimodal sensor. (a) $\Delta R/R_0$ in the range of 30-60 °C. (b) $\Delta R/R_0$ with increments of 1 °C from 30 to 38 °C. (c) Cyclic test of temperature conducted between 30 and 50 °C.

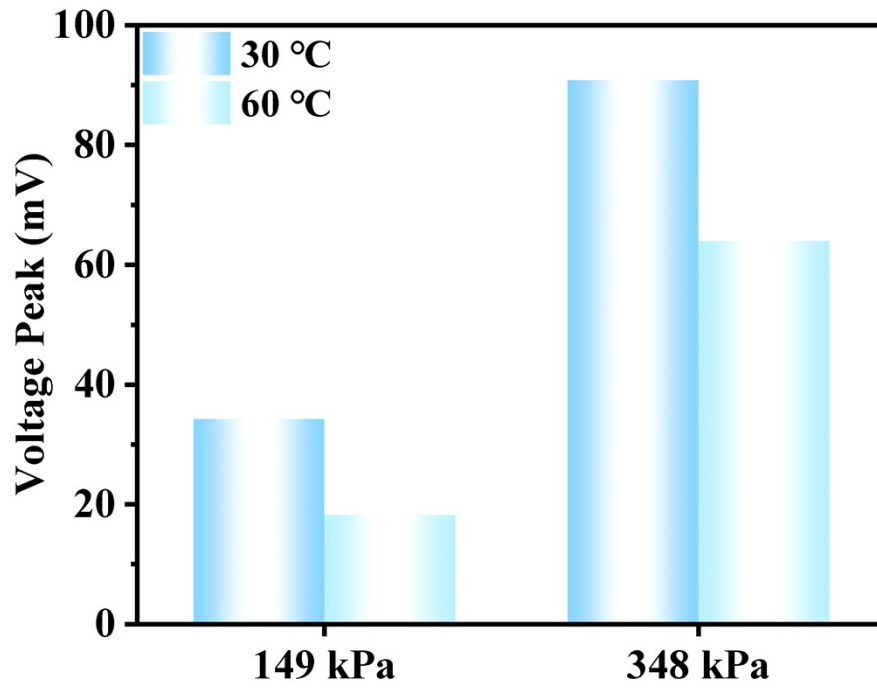


Figure S10. The comparison of voltage peak for the bimodal sensor at the temperature of 30 °C and 60 °C

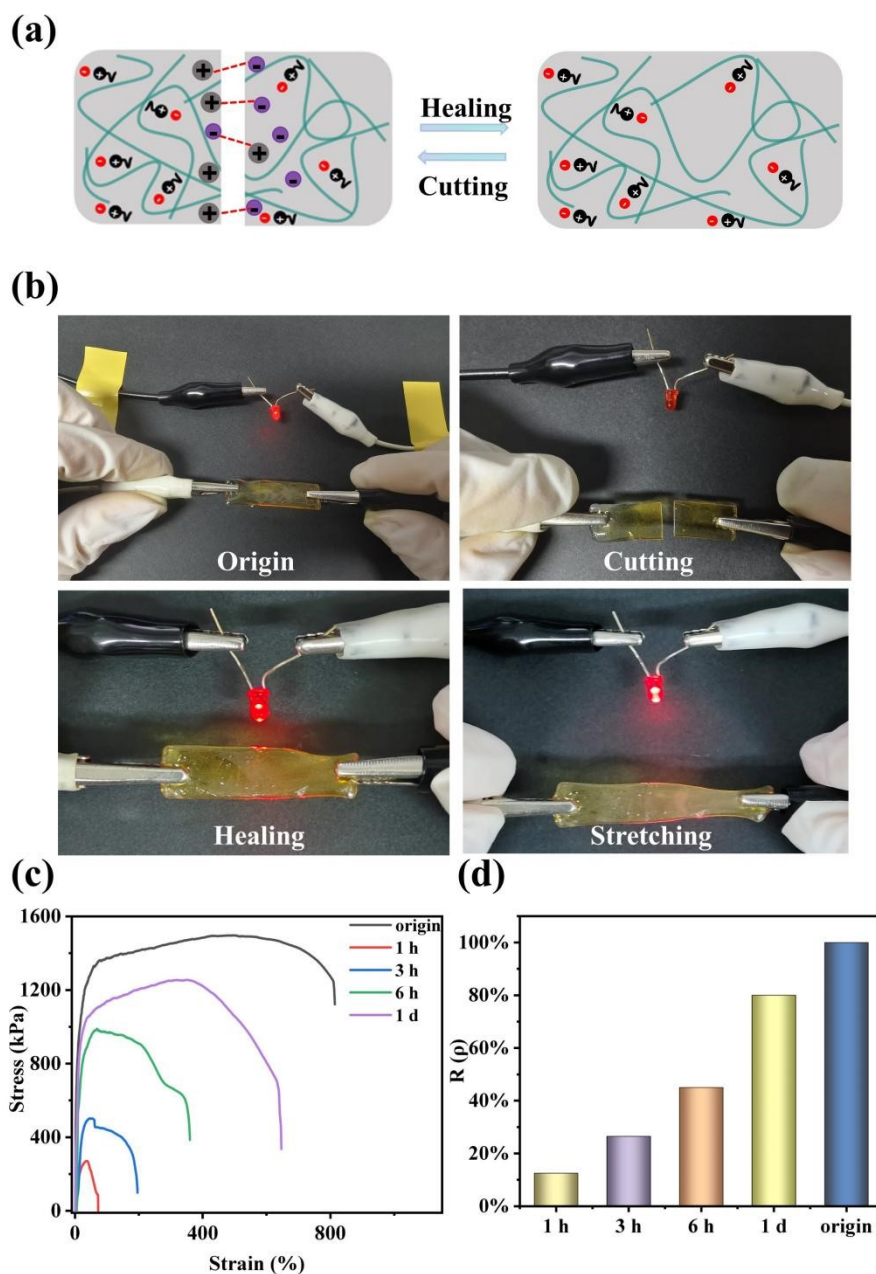


Figure S11. (a) Self-healing mechanism of PVIM+IL samples. (b) Images of PVIM+IL before and after self-healing at ambient temperature (25°C). (c) Tensile stress–strain curves of the PVIM+IL at various healing times. (d) Self-healing efficiency of PVIM+IL for various healing time.

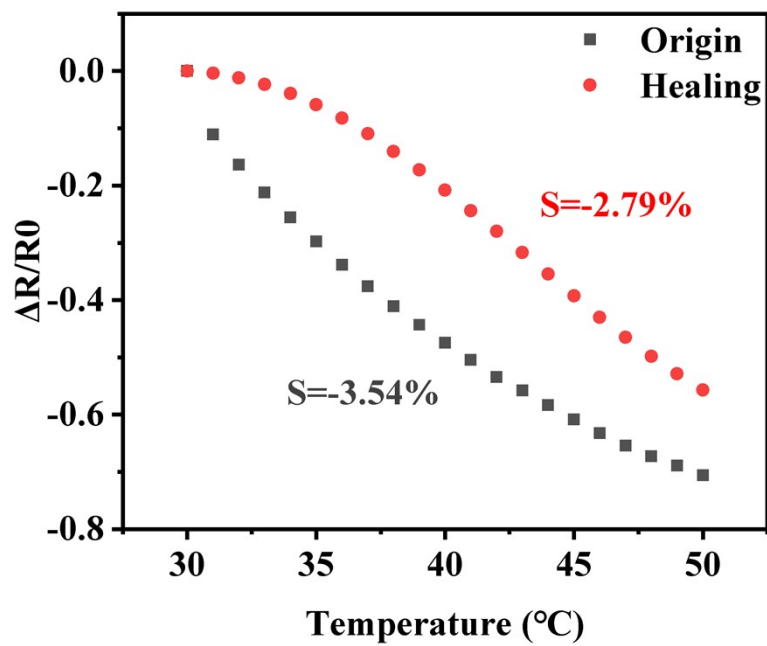


Figure S12. Temperature response of the bimodal sensor before and after self-healing.

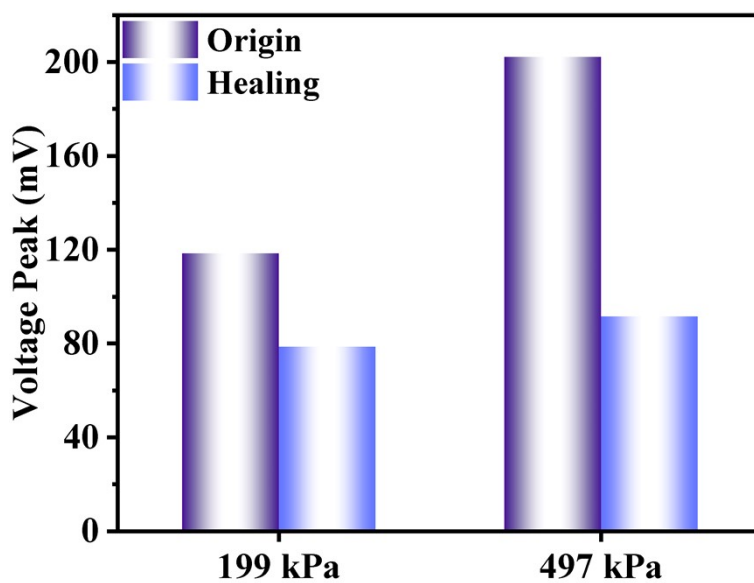


Figure S13. Voltage peak of the bimodal sensor before and after self-healing.

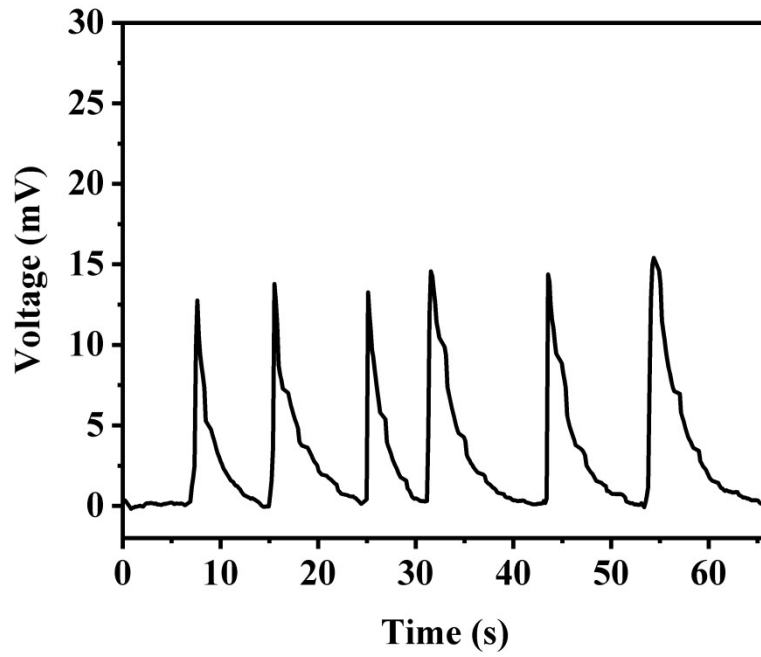


Figure S14. The voltage response of the bimodal sensor when monitoring repeat wrist bending.

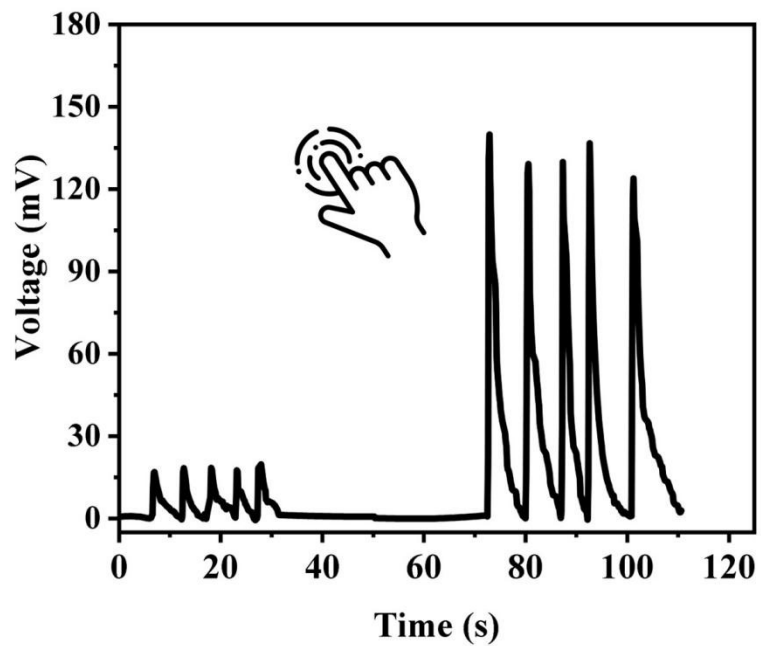


Figure S15. The voltage response of PIL sensor when monitoring finger pressing.

Table S1. Comparison between the present work and reported bimodal ionic sensors.

Working mechanism	Detection Range	Fabrication Complexity	Decoupled	Partial self-powered	References
Piezoresistive/ Thermal-resistive	80 kPa/ 70 °C	Two sensitive material	-	No	1
Piezoresistive/ Thermal-resistive	4 kPa/ 50 °C	Single material	-	No	2
Piezocapacitive/ Thermal-resistive	0-600 kPa/ 80 °C	Two sensitive material	Decoupled	No	3
Capacitive / Capacitive	133.5 kPa/ 75 °C	Single material	Machine-learning decoupled	No	4
Piezoresistive/ <u>Thermoelectric</u>	120 kPa/ -(not provided)	Two sensitive material	Decoupled	No	5
Piezocapacitive/ Thermal-resistive	300 kPa/ 50 °C	Two sensitive material	Decoupled	No	6
Piezoionic/ thermal-resistive	497 kPa/ 60 °C	Single material	Decoupled	Yes	This work

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